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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Susie Xiuru YANG et al.

Serial No. 10/809,908

Filed: March 26, 2004



: Group Art Unit: 2812

: Examiner:

For: IMPROVED CONTROL OF METAL RESISTANCE IN SEMICONDUCTOR
PRODUCTS VIA INTEGRATED METROLOGY

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Honorable Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the documents listed on the attached form PTO-1449. It is respectfully requested that the documents be expressly considered during the prosecution of this application, and that the documents be made of record therein and appear among the "References Cited" on any patent to issue therefrom. Copies of any cited U.S. Patents and U.S. Patent Publications are not being submitted in accordance with 37 CFR 1.98(a)(2)(i).

This Information Disclosure Statement is being filed within three months of the U.S. filing date OR before the mailing date of a first Office Action on the merits. No certification or fee is required.

In accordance with 37 C.F.R. § 1.97(g) and (h), the filing of this IDS should not be construed as a representation that a search had been made or that information cited is, or is considered to be, material to patentability as defined in 37 C.F.R. § 1.56 (b), or that any cited document listed or attached is (or constitutes) prior art. Unless otherwise indicated, the date of

publication indicated for an item is taken from the face of the item, and Applicant reserves the right to prove that the date of publication is in fact different.

No fee is believed to be required; however, the Commissioner is authorized to charge any deficiency in any fees pursuant to 37 CFR § 1.17 associated with this communication and to credit any excess payment to Deposit Account No. 08-0219.

Respectfully submitted,

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INFORMATION DISCLOSURE CITATION IN AN APPLICATION (PTO-1449)				ATTY. DOCKET NO. 008066 USA/ MTCG/PCTRL		SERIAL NO. 10/809,908	
				APPLICANT Susie Xiuru YANG et al.			
				FILING DATE March 26, 2004		GROUP 2812	
U.S. PATENT DOCUMENTS							
EXAMINER'S INITIALS	PATENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE	
	5,975,994	11/02/99	Sandhu et al.			06/11/97	
	6,113,462	09/05/00	Yang			12/18/97	
	6,230,069 B1	05/08/01	Campbell et al.			06/26/98	
	6,268,270 B1	07/31/01	Scheid et al.			10/29/99	
	6,277,014 B1	08/21/01	Chen et al.			10/09/98	
	6,291,367 B1	09/18/01	Kelkar			06/01/00	
	6,465,263 B1	10/15/02	Coss, Jr. et al.			01/04/00	
	6,532,555 B1	03/11/03	Miller et al.			10/29/99	
	6,535,783 B1	03/18/03	Miller et al.			03/05/01	
	6,541,401 B1	04/01/03	Herner et al.			07/31/00	
	6,546,508 B1	04/08/03	Sonderman et al.			10/29/99	
	6,556,881 B1	04/29/03	Miller			09/09/99	
	6,652,355 B2	11/25/03	Wiswesser et al.			06/04/01	
	6,725,402 B1	04/20/04	Coss, Jr. et al.			07/31/00	
EXAMINER				DATE CONSIDERED			

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.

<p style="text-align: center;">INFORMATION DISCLOSURE CITATION IN AN APPLICATION</p> <p style="text-align: center;">(PTO-1449)</p> 	<p>ATTY. DOCKET NO. 008066 USA/ MTCG/PCTRL</p>	<p>SERIAL NO. 10/809,908</p>
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	<p>FILING DATE March 26, 2004</p>	<p>GROUP 2812</p>
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)		
	IslamRaja, M. M., C. Chang, J. P. McVittie, M. A. Cappelli, and K. C. Saraswat. May/June 1993. "Two Precursor Model for Low-Pressure Chemical Vapor Deposition of Silicon Dioxide from Tetraethylorthosilicate." <i>J. Vac. Sci. Technol. B</i> , Vol. 11, No. 3, pp. 720-726.	
	Kim, Eui Jung and William N. Gill. July 1994. "Analytical Model for Chemical Vapor Deposition of SiO ₂ Films Using Tetraethoxysilane and Ozone" (Abstract). <i>Journal of Crystal Growth</i> , Vol. 140, Issues 3-4, pp. 315-326.	
	Guo, R.S, A. Chen, C.L. Tseng, I.K. Fong, A. Yang, C.L. Lee, C.H. Wu, S. Lin, S.J. Huang, Y.C. Lee, S.G. Chang, and M.Y. Lee. June 16-17, 1998. "A Real-Time Equipment Monitoring and Fault Detection System." <i>Semiconductor Manufacturing Technology Workshop</i> , pp. 111-121.	
	Lantz, Mikkel. 1999. "Equipment and APC Integration at AMD with Workstream." <i>IEEE</i> , pp. 325-327.	
	July 15, 2004. Office Action for U.S. Serial No. 10/172,977, filed June 18, 2002.	
	August 2, 2004. Office Action for U.S. Serial No. 10/174,377, filed June 18, 2002.	
	August 9, 2004. Written Opinion for PCT Serial No. PCT/US02/19063.	
	August 18, 2004. International Preliminary Examination Report for PCT Serial No. PCT/US02/19116.	
	August 24, 2004. Office Action for U.S. Serial No. 10/135,405, filed May 1, 2002.	
	August 25, 2004. Office Action for U.S. Serial No. 09/998,384, filed November 30, 2001.	
	September 9, 2004. Written Opinion for PCT Serial No. PCT/US02/21942.	
	September 16, 2004. International Preliminary Examination Report for PCT Serial No. PCT/US02/24859.	
EXAMINER	DATE CONSIDERED	

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